## Declaration and Power of Attorney For Patent Application 特許出願宣言書及び委任状

## Japanese Language Declaration 日本語宜言書

下記の氏名の発明者として、私は以下の通り宣言します。	As a below named inventor, I hereby declare that:
私の住所、私書箱、国籍は下記の私の氏名の後に記載された通りです。	My residence, post office address and citizenship are as stated next to my name.
下記の名称の発明に関して請求範囲に記載され、特許出願している発明内容について、私が最初かつ唯一の発明者(下記の氏名が一つの場合)もしくは最初かつ共同発明者であると(下記の名称が複数の場合)信じています。	I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled
	QUINOXALINEDEVIVATIVES,ORGANICSEMICONDUCTORDEVICEANDELECTROLUMINESCENT DEVICE
上記発明の明細書(下記の欄で×印がついていない場合は、本書に添付)は、	The specification of which is attached hereto unless the following box is checked:
□月日に提出され、米国出願番号または特許協定条約国際出願番号を とし、(該当する場合)に訂正されました。	□ was filed onas United States Application Numberor PCT International Application Numberand was amended on(if applicable).
私は、特許請求範囲を含む上記訂正後の明細書を検討し、 内容を理解していることをここに表明します。	I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment referred to above.
私は、連邦規則法典第 37 編第 1 条 56 項に定義されるとおり、特許資格の有無について重要な情報を開示する義務があることを認めます。	I acknowledge the duty to disclose information which is material to patentability as defined in Title 37, Code of Federal Regulations, Section 1.56.

## Japan se Language Declaration (日本語宜言書)

私は、米国法典第35編119条(a)·(d)項又は365条(b)項に基き下記の、米国以外の国の少なくとも一カ国を指定している特許協力条約365(a)項に基く国際出願、又は外国での特許出願もしくは発明者証の出願についての外国優先権をここに主張するとともに、優先権を主張している、本出願の前に出願された特許または発明者証の外国出願を以下に、枠内をマークすることで、示しています。

I hereby claim foreign priority under Title 35, United States Code, Section 119(a)-(d) or 365(b) of any foreign application(s) for patent or inventor's certificate, or 365(a) of any PCT International application which designated at least one country other than the United States, listed below and have also identified below, by checking the box, any foreign application for patent or inventor's certificate, or PCT International application having a filing date before that of the application on which priority is claimed.

Prior Foreign Application(s) 外国での先行出願			Priority Not Claim d 優先権主張なし
	 (Country) (国名)	November 13, 2002 (Day/Month/Year Filed) (出願年月日)	
(Number) (番号)	(Country) (国名)	(Day/Month/Year Filed) (出願年月日)	
(Number) (番号)	(Country) (国名)	(Day/Month/Year Filed) (出願年月日)	
私は、第 35 編米国法典 119 条(6 特許出願規定に記載された権利をこ		I hereby claim the benefit under Code, Section 119(e) of any application(s) listed below.	
(Application No.) (出願番号)	(Filing Date) (出願日)	(Application No.) (出願番号)	(Filing Date) (出願日)
私は、下記の米国法典第35編126 特許出願に記載された権利、又は米 力条約365条(c)に基く権利をここに の各請求範囲の内容が米国法典代 特許協力条約で規定された方法で免 開示されていない限り、その先行米国 願書の日本国内または特許協力条約 中に入手された、連邦規制法典第30 れた特許資格の有無に関する重要な があることを認識しています。	国を指定している特許協主張します。また、本出願35編112条第1項又は元行する米国特許出願に出田原提出日以降で本出的国際提出日までの期間7編1条56項で定義さ	I hereby claim the benefit under Code, Section 120 of any Unite 365(c) of any PCT International a United States, listed below an matter of each of the claims disclosed in the prior United Stapplication in the manner provide Title 35, United States Code Sethe duty to disclose informational patentability as defined in Tit Regulations, Section 1.56 where the filing date of the national or PCT International filing.	d States application(s), or application designating the displication designating the displication designating the displication is not ates or PCT International ded by the first paragraph of ection 112, I acknowledge on which is material to le 37, Code of Federal which became available prior application and the
 (Application No.) (出願番号)	(Filing Date) (出願日)	(Status: Patented, Pend (現況・特許許可洛 á	_ ·

(Application No.)	(Filing Date)	(Status: Patented, Pending, Abandoned)
(出願番号)	(出願日)	(現況: 特許許可済、継続中、放棄済)
(Application No.)	(Filing Date)	(Status: Patented, Pending, Abandoned)
(出願番号)	(出願日)	(現況: 特許許可済、継続中、放棄済)
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(出願番号)	(出願日)	(現況: 特許許可済、継続中、放棄済)

私は、私自身の知識に基いて本宣言書中で私が行う表明が 真実であり、かつ私の入手した情報と私の信じるところに基く 表明が全て真実であると信じていること、さらに故意になされた 虚偽の表明及びそれと同等の行為は米国法典第 18 編第 1001 条に基き、罰金または拘禁、もしくはその両方により処罰 されること、そしてそのような故意による虚偽の声明を行えば、 出願した、又は既に許可された特許の有効性が失われること を認識し、よってここに上記のごとく宣誓を致します。 I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

## Japanese Language Declaration (日本語官言書)

委任状: 私は下記の発明者として、本出願に関する一切の手続きを米特許商標局に対して遂行する弁護士または代理人として、下記の者を指名いたします。 (弁護士、または代理人の氏名及び登録番号を明記のこと)

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POWER OF ATTORNEY: As a named inventor, I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and transact all business in the Patent and Trademark Office connected therewith (list name and registration number).

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The undersigned hereby authorizes any U. S. attorney or agent named herein to accept and follow instructions from \_\_\_\_\_\_ as to any action to be taken in the Patent and Trademark Office regarding this application without direct communication between the U. S. attorney or agent and the undersigned. In the event of a change in the persons from whom instructions may be taken, the U. S. attorneys or agents named herein will be so notified by the undersigned.

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